MOSFETs Silicon N-channel MOS (U-MOSⅧ)

XPN3R804NC

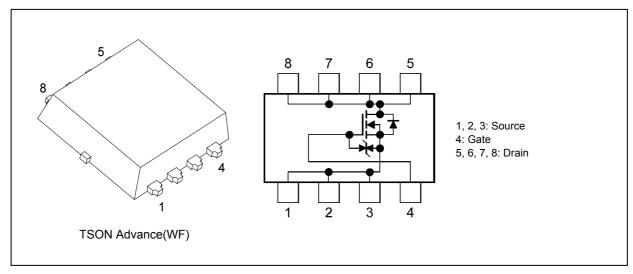
1. Applications

- Automotive
- Switching Voltage Regulators
- DC-DC Converters
- Motor Drivers

2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Low drain-source on-resistance: $R_{DS(ON)}$ = 3.0 mO (typ.) (V_{GS} = 10 V)
- (4) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 40 \ V)$
- (5) Enhancement mode: V_{th} = 1.5 to 2.5 V (V_{DS} = 10 V, I_{D} = 0.3 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characteri	Symbol	Rating	Unit		
Drain-source voltage			V _{DSS}	40	V
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)		(Note 1)	I _D	40	Α
Drain current (pulsed)		(Note 1)	I _{DP}	80]
Power dissipation	(T _c = 25 °C)		PD	100	W
Power dissipation	(t = 10 s)	(Note 2)		2.27	1
Power dissipation	(t = 10 s)	(Note 3)		0.84	1
Single-pulse avalanche energy		(Note 4)	E _{AS}	177	mJ
Single-pulse avalanche current			I _{AS}	40	A
Channel temperature		(Note 5)	T _{ch}	175	°C
Storage temperature		(Note 5)	T _{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit		
Channel-to-case thermal impedance	(T _c = 25 °C)		Z _{th(ch-c)}	1.5	°C/W
Channel-to-ambient thermal impedance	(t = 10 s)	(Note 2)	Z _{th(ch-a)}	66	
Channel-to-ambient thermal impedance	(t = 10 s)	(Note 3)	Z _{th(ch-a)}	178	

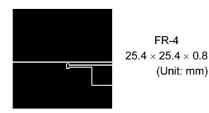
Note 1: Ensure that the channel temperature does not exceed 175 °C.

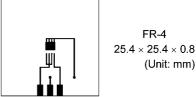
Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

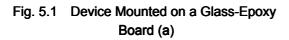
Note 4: V_{DD} = 32 V, T_{ch} = 25 °C (initial), L = 85 μ H, R_G = 1 Ω , I_{AS} = 40 A

Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.





2 Device Mounted on a Glass-Epoxy





Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±16 V, V_{DS} = 0 V			±10	μA
Drain cut-off current	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V			10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	40		_	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	20		_	1
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.3 mA	1.5	_	2.5	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 20 A	_	4.8	7.8	mΩ
		V _{GS} = 10 V, I _D = 20 A		3.0	3.8]

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	2230	_	pF
Reverse transfer capacitance	C _{rss}		_	110	_	
Output capacitance	C _{oss}			1250	_	
Gate resistance	rg		_	2.4	_	Ω
Switching time (rise time)	tr	See Fig. 6.2.1	_	17	_	ns
Switching time (turn-on time)	t _{on}			38	_	
Switching time (fall time)	t _f]		17	_	
Switching time (turn-off time)	t _{off}]		66	_	ns

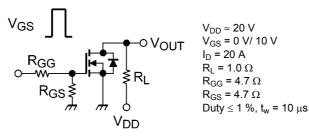


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

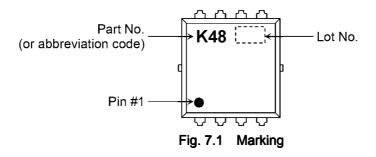
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 32$ V, V_{GS} = 10 V, I_D = 40 A		35	_	nC
Gate-source charge 1	Q _{gs1}		_	8	_	
Gate-drain charge	Q _{gd}		_	7.2	_	

6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

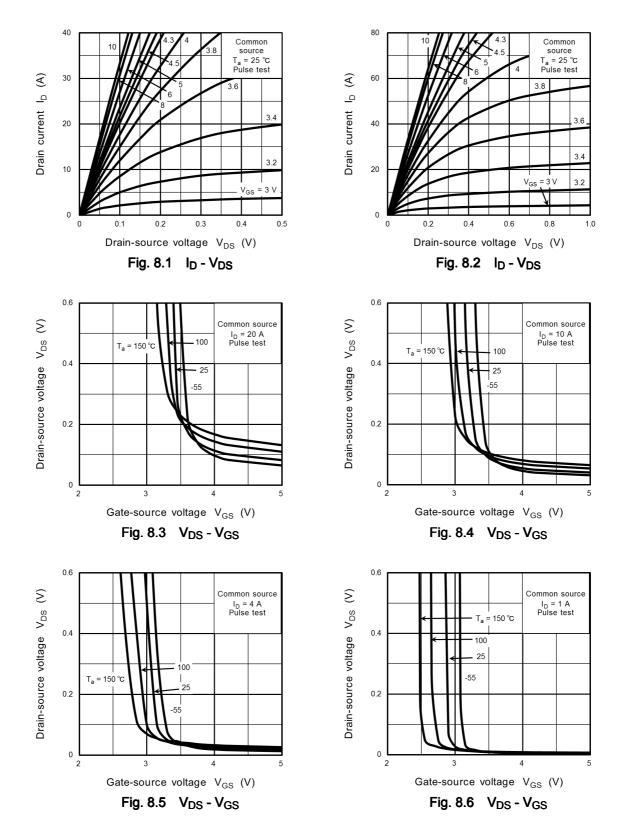
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed)	(Note 6)	I _{DRP}	—	_	_	80	А
Diode forward voltage		V _{DSF}	I _{DR} = 40 A, V _{GS} = 0 V	_		-1.2	V

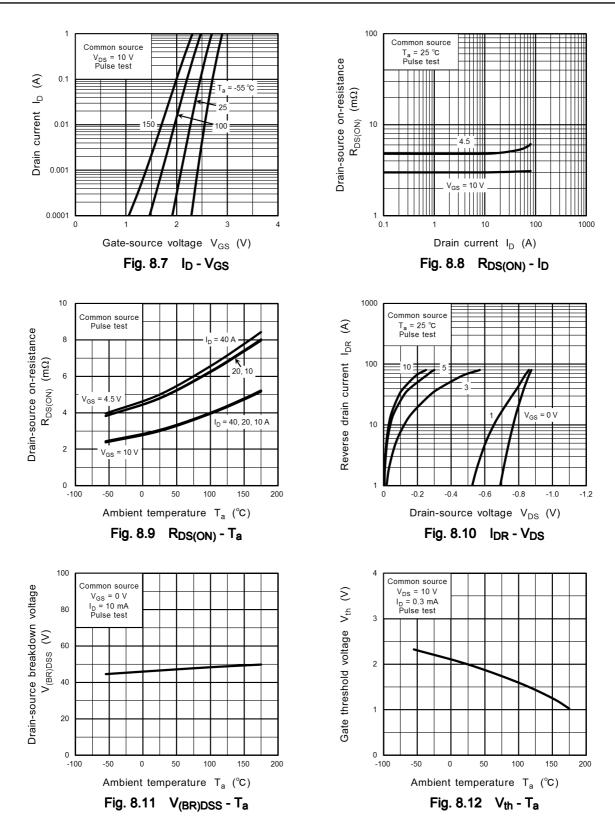
Note 6: Ensure that the channel temperature does not exceed 175 °C.

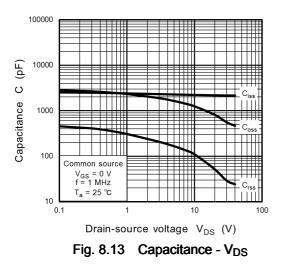
7. Marking

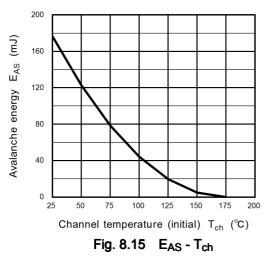


8. Characteristics Curves (Note)









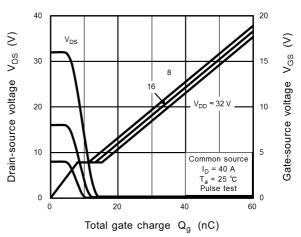


Fig. 8.14 Dynamic Input/Output Characteristics

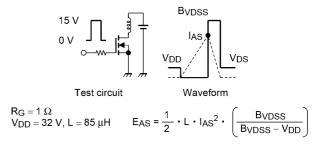
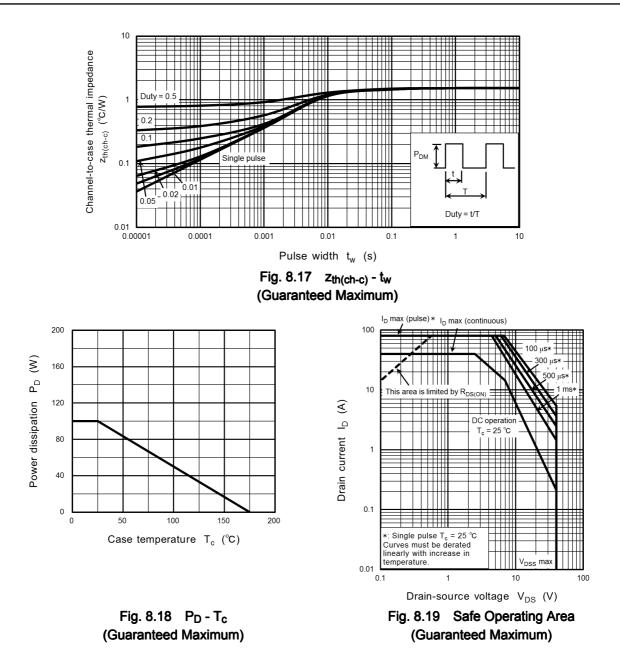


Fig. 8.16 Test Circuit/Waveform

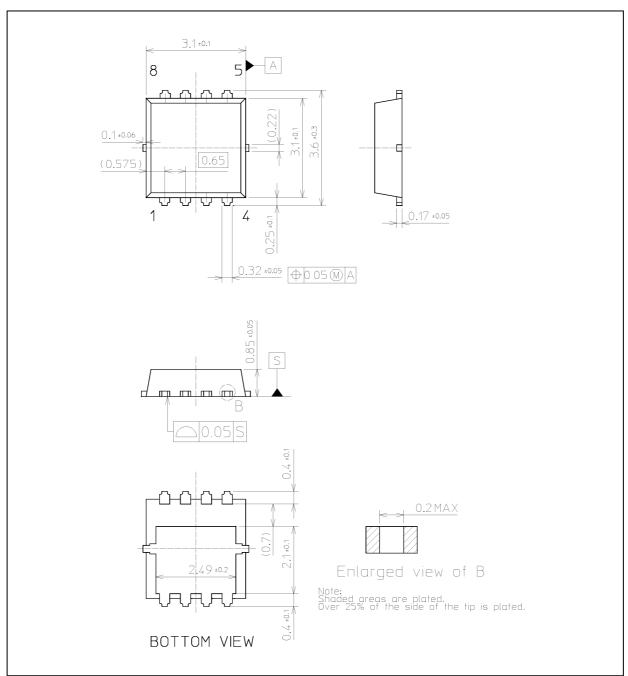


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

XPN3R804NC

Package Dimensions

Unit: mm



Weight: 0.029 g (typ.)

Package Name(s)

TOSHIBA: 2-3X2A

Nickname: TSON Advance(WF)

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